A

DESCRIPTION

The AL1G08 is single 2-input positive-AND gate, designed for 1.65V to 5.5V V_{CC} operation.

www.ait-ic.com

The AL1G08 performs the Boolean function $Y=A \cdot B$ or $Y=\overline{A}+\overline{B}$ in positive logic. The device is fully specified for partial-power-down applications using loff. The loff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The AL1G08 is available in Green SOT-25 and SC70-5 packages.

FEATURES

- Operating Voltage Range:1.65V to 5.5V
- Low Power Consumption:1µA (Max)
- Operating Temperature Range:
 -40°C to +125°C
- Inputs Accept Voltage to 5.5V
- High Output Drive: ±24mA at Vcc=3.0V

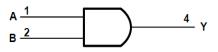
APPLICATION

- Active Noise Elimination
- Bar Code Scanner
- Blood Pressure Monitor
- CPAP Machine
- Fingerprint identification
- Network attached storage (NAS)

	-			
Package Type	Part Number			
SOT-25	E E	AL1G08E5R		
SPQ: 3,000pcs/Reel	E5	AL1G08E5VR		
SC70-5	<u>OF</u>	AL1G08C5R		
SPQ: 3,000pcs/Reel	C5	AL1G08C5VR		
Note	V: Halogen	free Package		
Note	R: Tape & Reel			
AiT provides all RoHS products				

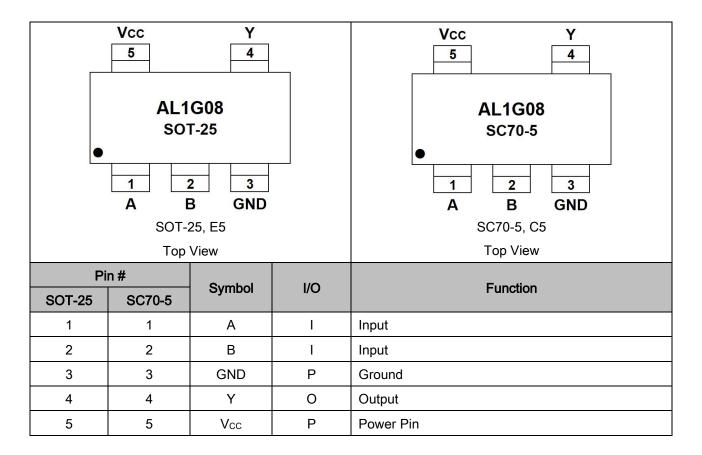
ORDERING INFORMATION

FUNCTIONAL BLOCK DIAGRAM





PIN DESCIPTION



FUNCTION TABLE

Input		Output
А	В	Y
Н	Н	н
L	Н	L
Н	L	L
L	L	L

Y=A•B H=High Voltage Level L=Low Voltage Level



ABSOLUTE MAXIMUM RATINGS

T _A = +25°C, unless otherwise noted.	. (1)	
V _{CC} , Supply Voltage Range		-0.5V ~ +6.5V
V _I , Input Voltage Range ⁽¹⁾		-0.5V ~ +6.5V
V _o , Voltage range applied to any or power-off state ⁽¹⁾	utput in the high-impedance or	-0.5V ~ +6.5V
Vo, Voltage range applied to any o	utput in the high or low state (1)(2)	-0.5V ~ V _{CC} +0.5V
Iк, Input Clamp Current	V1<0	-50mA
Іок, Output Clamp Current	Vo<0	-50mA
Io, Continuous Output Current		±50mA
Continuous Current Through Vcc o	r GND	±100mA
TJ, Junction Temperature		-65°C ∼ +150°C
T _{STG} , Storage Temperature		-65℃ ~ +150℃
ESD Ratings		
	Human-Body Model (HBM)	±8000V
$V_{(ESD)}$, Electrostatic Discharge	Machine Model (MM)	±500V
Thermal Information		
R _{0JA} , Junction-to-Ambient	SOT-25	273.8°C/W
Thermal Resistance	SC70-5	214.7°C/W
R _{0JC(top)} ,Junction-to-Case(Top)	SOT-25	126.8°C/W
Thermal Resistance	SC70-5	127.1°C/W
Rejb, Junction-to-Board	SOT-25	85.9°C/W
Thermal Resistance	SC70-5	60.0°C/W
Ψ _{JT} , Junction-to-Top	SOT-25	10.9°C/W
Characterization Parameter	SC70-5	33.4°C/W
Ψ _{JB} ,Junction-to-Board	SOT-25	84.9°C/W
Characterization Parameter	SC70-5	59.8°C/W

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

(1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(2) The value of V_{CC} is provided in the Recommended Operating Conditions table.



RECOMMENDED OPERATING CONDITIONS

$T_{A} = +25^{\circ}C,$	unless	otherwise	noted	(1)
1A = +25 C,	u111033	00110110130	noteu.	(.)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Cumply) (alterna	M	Operating	1.65	-	5.5	V	
Supply Voltage	Vcc	Data retention only	1.5	-	5.5	v	
		Vcc=1.65V to 1.95V	0.65xVcc	-	-		
	V	Vcc=2.3V to 2.7V	1.7	-	-	V	
High-Level Input Voltage	Vih	Vcc=3.0V to 3.6V	2.2	-	-	v	
		V _{CC} =4.5V to 5.5V	0.7xV _{CC}	-	-		
	VIL	Vcc=1.65V to 1.95V	-	-	0.15xVcc		
		Vcc=2.3V to 2.7V	-	-	0.3	V	
Low-Level Input Voltage		Vcc=3.0V to 3.6V	-	-	0.4		
		Vcc=4.5V to 5.5V	-	-	0.15xVcc		
Input Voltage	Vı	-	0	-	5.5	V	
Output Voltage	Vo	-	0	-	Vcc	V	
	tr, tf	V _{CC} =1.8V± 0.15V,2.5V ± 0.2V	/		20		
Input Transition Rise or Fall		V _{CC} =3.3V± 0.3V	-	-	10	ns/V	
		V _{CC} =5.0V± 0.5V	-	-	5		
Operating Temperature	TA	-	-40	-	+125	°C	

AC ELECTRICAL CHARACTERISTICS

T_A = +25°C, unless otherwise noted. ⁽¹⁾

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit	
		V _{CC} =1.8V±0.15V	C∟=30pF, R∟=1kΩ	-	11.6	-		
Drangestion Dalay	4	V _{CC} =2.5V±0.2V	C∟=30pF, R∟=500Ω	-	6.6	-		
Propagation Delay	t _{pd}	V _{CC} =3.3V±0.3V	C∟=50pF, R∟=500Ω	-	5.4	-	ns	
		V _{CC} =5V±0.5V	C∟=50pF, R∟=500Ω	-	4.3	-		
Input Capacitance	Ci	V _{CC} =0V	-	-	4	-	pF	
Power Dissipation	0	V _{CC} =3.3V	6-40MU-	-	26	-	- - -	
Capacitance	C _{pd}	V _{CC} =5.0V	f=10MHz	-	31	-	pF	



DC ELECTRICAL CHARACTERISTICS

$T_{A} = +25^{\circ}C$,	unless	otherwise	noted.	(1)
IA 1200,	0.000	00100101000		

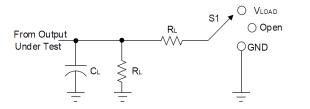
	Parameter	Cond	ditions	Min.	Тур.	Max.	Unit
		Iон= -100uA, Vcc=1.65	I _{OH} = -100μA, V _{CC} =1.65V to 5.5V		-	-	
				- 0.1			
Vон		I _{OH} =-4mA, V _{CC} =1.65V		1.2	-	-	
	0°C to +125°C	Iон =-8mA , Vcc =2.3 V		1.9	-	-	V
I A4	0 0 0 0 + 125 0	Iон=-16mA, Vcc=3V		2.4	-	-	
		Iон=-24mA, Vcc=3V		2.3	-	-	
		I _{OH} =-32mA, V _{CC} =4.5V		3.8	-	-	
		I _{OL} =100μA, V _{CC} =1.65V	to 5.5V	-	-	0.1	
		I _{OL} =4mA, V _{CC} =1.65V	I _{OL} =4mA, V _{CC} =1.65V			0.45	V
V _{OL} T _A =-40°C to +125°C		IoL=8mA, Vcc=2.3V	Io∟=8mA, Vcc=2.3V		-	0.3	
		I _{OL} =16mA, V _{CC} =3V		-	-	0.4	V
		I _{OL} =24mA, V _{CC} =3V		-	-	0.55	
		I _{OL} =32mA, V _{CC} =4.5V		-	-	0.55	
	A an D inserts	VI=5.5V or GND	T _A =+25°C	-	±0.1	±1	
Iı	A or B inputs	V _{CC} = 0V to 5.5V	T _A =-40°C to +125°C	-	-	±5	μA
	·	V _I or V _O =5.5V	T _A =+25°C	-	±0.1	±1	•
l _{off}		V _{CC} =0V	T _A =-40°C to +125°C	-	-	±10	μA
		V_1 =5.5V or GND, I_0 =0,	T _A =+25°C	-	0.1	1	
lcc		V_{CC} =1.65V to 5.5V	T _A =-40°C to +125°C	-	-	10	μA
One input at Vcc- 0.6V,							
∆lcc T = 4	0°0 to 1405°0	Other inputs at Vcc or 0	Other inputs at Vcc or GND		-	500	μA
I _A =-4	0°C to +125°C	V_{CC} =3V to 5.5V					

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



DETAILED INFORMATION

Parameter Measurement Information



TEST	S1
t _{PLH} / t _{PHL}	Open
t _{PLZ} / t _{PZL}	VLOAD
t _{PHZ} / t _{PZH}	GND

Mar	Inputs		V	M			Ľ		V
Vcc	Vı	t _r /t _f	Vм	Vload	C	Ļ	F	KL.	V۵
1.8V±0.15V	Vcc	≤2ns	Vcc/2	2 x Vcc	15pF	30pF	1MΩ	1kΩ	0.15V
2.5V±0.2V	Vcc	≤2ns	V _{CC} /2	$2 \times V_{CC}$	15pF	30pF	1MΩ	500Ω	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	15pF	50pF	1MΩ	500Ω	0.3V
5V±0.5V	Vcc	≤2.5ns	Vcc/2	2 x Vcc	15pF	50pF	1MΩ	500Ω	0.3V

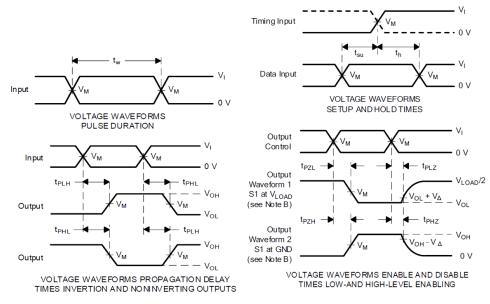


Figure 1. Load Circuit and Voltage Waveforms

(A) C_L includes probe and jig capacitance.

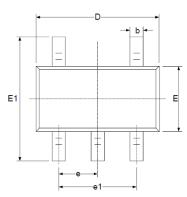
(B) Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

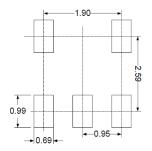
- (C) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω .
- (D) The outputs are measured one at a time, with one transition per measurement.
- (E) t_{PLZ} and t_{PHZ} are the same as $t_{\text{dis}}.$
- (F) t_{PZL} and t_{PZH} are the same as t_{en} .
- (G) t_{PLH} and t_{PHL} are the same as $t_{\mathsf{pd}}.$
- (H) All parameters and waveforms are not applicable to all devices.



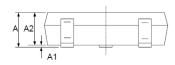
PACKAGE INFORMATION

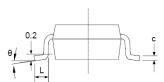
Dimension in SOT-25 (Unit: mm)





RECOMMENDED LAND PATTERN

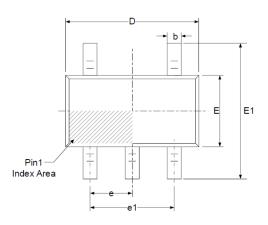


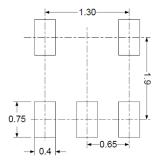


Cumhal	Millim	ieters
Symbol	Min	Max
А	1.050	1.250
A1	0.000	0.100
A2	1.050	1.150
b	0.300	0.500
с	0.100	0.200
D	2.820	3.020
E	1.500	1.700
E1	2.650	2.950
е	0.950	BSC
e1	1.800	2.000
L	0.300	0.600
θ	0°	8°

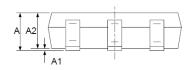


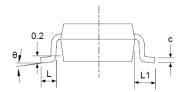
Dimension in SC70-5 (Unit: mm)





RECOMMENDED LAND PATTERN





Cumbol	Millimeters			
Symbol	Min	Max		
A	0.900	1.100		
A1	0.000	0.100		
A2	0.900	1.000		
b	0.150	0.350		
с	0.080	0.150		
D	2.000	2.200		
E	1.150	1.350		
E1	2.150	2.450		
е	0.650	BSC		
e1	1.300	BSC		
L	0.260 0.460			
L1	0.525			
θ	0°	8°		



IMPORTANT NOTICE

AiT Semiconductor Inc. (AiT) reserves the right to make changes to any its product, specifications, to discontinue any integrated circuit product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

AiT Semiconductor Inc.'s integrated circuit products are not designed, intended, authorized, or warranted to be suitable for use in life support applications, devices or systems or other critical applications. Use of AiT products in such applications is understood to be fully at the risk of the customer. As used herein may involve potential risks of death, personal injury, or servere property, or environmental damage. In order to minimize risks associated with the customer's applications, the customer should provide adequate design and operating safeguards.

AiT Semiconductor Inc. assumes to no liability to customer product design or application support. AiT warrants the performance of its products of the specifications applicable at the time of sale.